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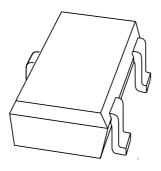
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BAT854W seriesSchottky barrier (double) diodes

Product data sheet 2001 Feb 27



Schottky barrier (double) diodes

BAT854W series

FEATURES

- · Very low forward voltage
- · Very low reverse current
- · Guard ring protected
- · Very small SMD plastic package.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- · Blocking diodes
- Low power consumption applications (e.g. hand-held applications).

DESCRIPTION

Planar Schottky barrier diodes encapsulated in a SOT323 very small SMD plastic package. Single diodes and double diodes with different pinning are available.

MARKING

TYPE NUMBER	MARKING CODE
BAT854W	81
BAT854AW	82
BAT854CW	83
BAT854SW	84

PINNING

PIN	SYMBOL					
BAT854W						
1	а					
2	n.c.					
3	k					
BAT854AW						
1	k ₁					
2	k ₂					
3	a ₁ ,a ₂					
BAT854CW						
1	a ₁					
2	a ₂					
3	k ₁ , k ₂					
BAT854SW						
1	a ₁					
2	k ₂					
3	k ₁ , a ₂					

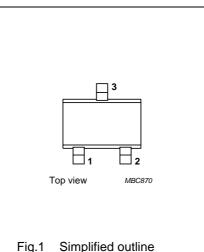


Fig.1 Simplified outline SOT323 and pin configuration.

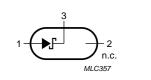


Fig.2 BAT854W single diode configuration (symbol).

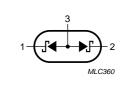


Fig.3 BAT854AW diode configuration (symbol).

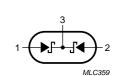


Fig.4 BAT854CW diode configuration (symbol).

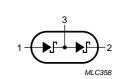


Fig.5 BAT854SW diode configuration (symbol).

Schottky barrier (double) diodes

BAT854W series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V _R	continuous reverse voltage		_	40	V
I _F	continuous forward current		_	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s; } \delta \le 0.5$	_	300	mA
I _{FSM}	non-repetitive peak forward current	t = 8.3 ms half sinewave; JEDEC method	-	1	A
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V _F	continuous forward voltage	see Fig.6			
		$I_F = 0.1 \text{ mA}$	200	_	mV
		$I_F = 1 \text{ mA}$	260	_	mV
		I _F = 10 mA	340	_	mV
		$I_F = 30 \text{ mA}$	_	420	mV
		I _F = 100 mA	_	550	mV
I _R	continuous reverse current	V _R = 25 V; note 1; see Fig.7	_	0.5	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see Fig.8	_	20	pF

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	625	K/W

Note

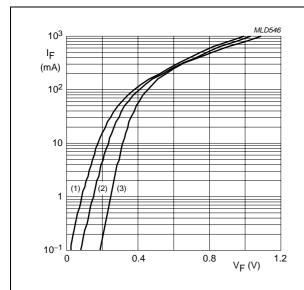
1. Refer to SOT323 standard mounting conditions.

^{1.} Pulse test: t_p = 300 μ s; δ = 0.02.

Schottky barrier (double) diodes

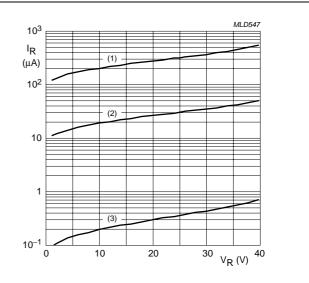
BAT854W series

GRAPHICAL DATA



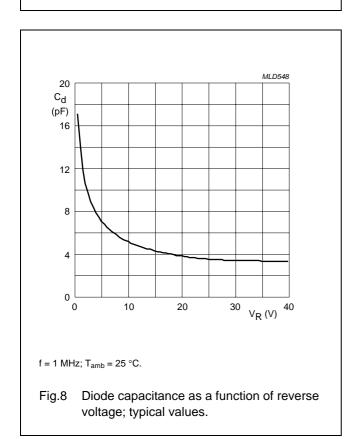
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.6 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.7 Reverse current as a function of reverse voltage; typical values.



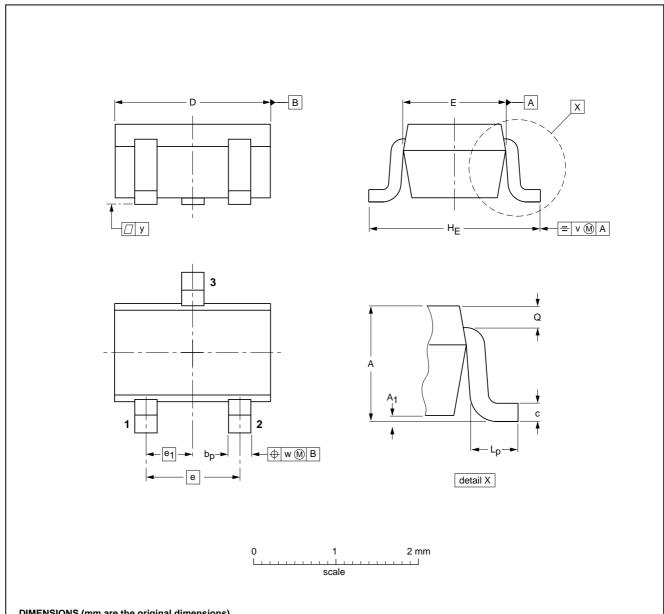
Schottky barrier (double) diodes

BAT854W series

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



DIMENS	10N2 (II	ım are tı	ne origir	iai dime	nsions)	

UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	JEDEC EIAJ PROJECTION		1330E DATE	
SOT323			SC-70			97-02-28

Schottky barrier (double) diodes

BAT854W series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

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